MBR40250, MBR40250T, MBRF40250T

250 V, 40 A SWITCHMODE™ Schottky Power Rectifier

Features

- 250 V Blocking Voltage
- Low Forward Voltage Drop, $V_F = 0.86 V$
- Soft Recovery Characteristic, $T_{RR} < 35$ ns
- Low Reverse Current, $I_R = 30 \ \mu A$
- Stable Switching Performance Over Temperature
- Pb–Free Packages are Available

Benefits

- Reduces or Eliminates Reverse Recovery Oscillations
- Minimizes Need for EMI Filtering
- Reduces Switching Losses
- Improved Efficiency

Applications

- Power Supply
- Power Management
- Automotive
- Instrumentation

Mechanical Characteristics

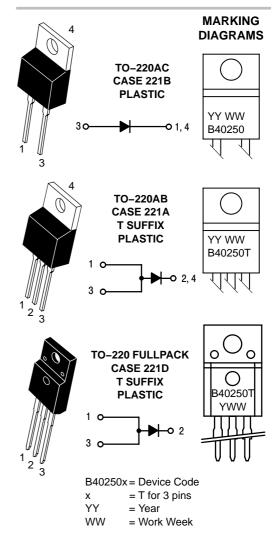
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Epoxy Meets UL 94 V-0 at 0.125 in



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SCHOTTKY RECTIFIER 40 AMPERES, 250 VOLTS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	250	V
Average Rectified Forward Current (Rated V_R) T _C = 82°C MBR40250, MBR40250T (Rated V_R) T _C = 46°C MBRF40250T	I _{F(AV)}	40	A
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) T _C = 82°C MBR40250, MBR40250T (Rated V _R , Square Wave, 20 kHz) T _C = 46°C MBRF40250T	I _{FRM}	80	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 20 kHz)	I _{FSM}	150	A
Storage Temperature	T _{stg}	-65 to +175	°C
Operating Junction Temperature	TJ	-65 to +150	°C
Voltage Rate of Change (Rated V _R)	dv/dt	10,000	V/µs

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
MBI MI Junction-to MBI	n-to-Case R _{θJC} R40250(T) BRF40250 o-Ambient R _{θJA} R40250(T) BRF40250	2.0 3.0 60 50	°C/W

ELECTRICAL CHARACTERISTICS

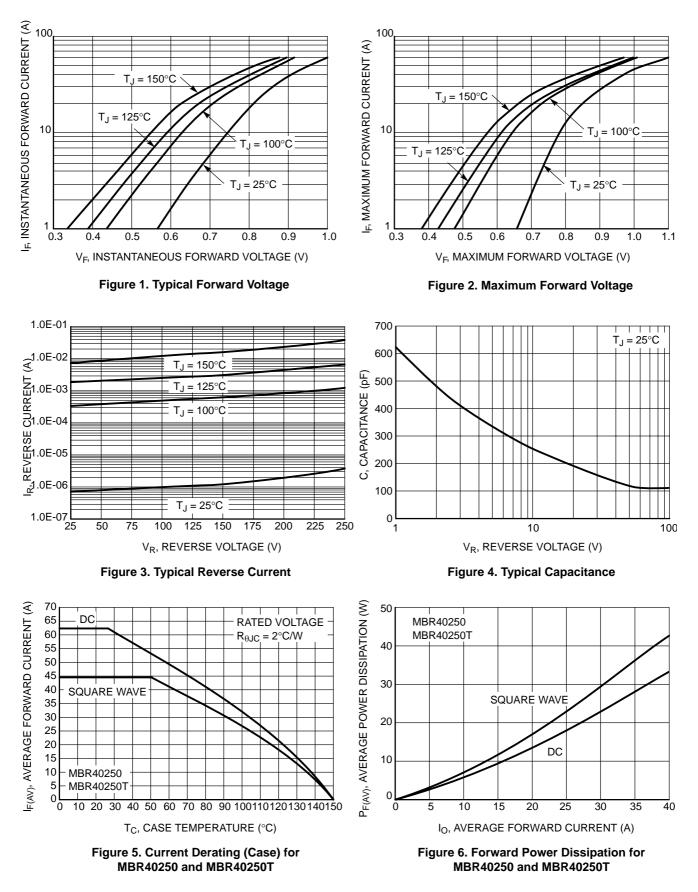
Rating	Symbol	Value	Unit	
Maximum Instantaneous Forward Voltage (Note 1) $I_F = 20 \text{ A}, T_C = 25^{\circ}\text{C}$ $I_F = 20 \text{ A}, T_C = 125^{\circ}\text{C}$ $I_F = 40 \text{ A}, T_C = 25^{\circ}\text{C}$ $I_F = 40 \text{ A}, T_C = 125^{\circ}\text{C}$	VF	0.86 0.71 0.97 0.86	V	
Maximum Instantaneous Reverse Current (Note 1) Rated DC Voltage, $T_C = 25^{\circ}C$ Rated DC Voltage, $T_C = 125^{\circ}C$	I _R	0.03 30	mA	
Maximum Reverse Recovery Time $I_F = 1.0 \text{ A}, \text{di/dt} = 50 \text{ A/}\mu\text{s}, \text{T}_C = 25^\circ\text{C}$	t _{rr}	35	ns	

Capacitance	V_R = -5.0 V, T_C = 25°C, Frequency = 1.0 MHz	CT	500	pF

1. Pulse Test: Pulse Width = 300 $\mu s,$ Duty Cycle \leq 2.0%.

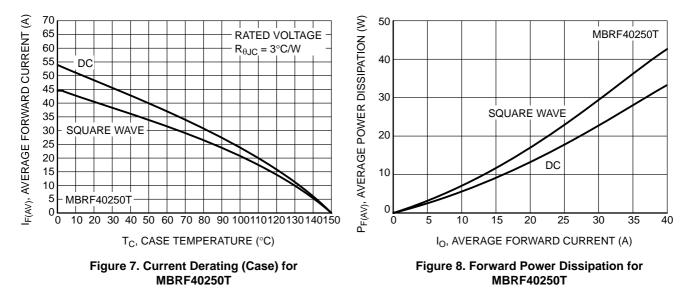
MBR40250, MBR40250T, MBRF40250T

TYPICAL CHARACTERISTICS



MBR40250, MBR40250T, MBRF40250T

TYPICAL CHARACTERISTICS

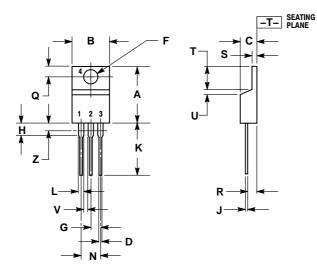


ORDERING INFORMATION

	Device	Package	Shipping [†]
MBR40250		TO-220AC	
MBR40250G		TO-220AC (Pb-Free)	50 Units / Rail
MBR40250T		TO-220AB	
MBR40250TG		TO-220AB (Pb-Free)	50 Units / Rail
MBRF40250T		TO-220 FULLPACK	
MBRF40250TG		TO–220 FULLPACK (Pb–Free)	50 Units / Rail

PACKAGE DIMENSIONS

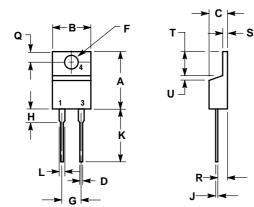
TO-220AB CASE 221A-09 **ISSUE AA**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES		MILLIMETER	
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Ζ		0.080		2.04

TO-220AC CASE 221B-04 ISSUE D



NOTES:

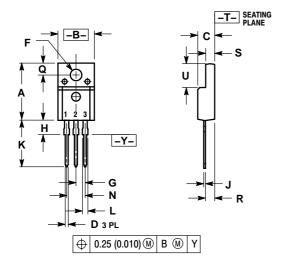
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2.	CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.620	15.11	15.75	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.82	
D	0.025	0.035	0.64	0.89	
F	0.142	0.147	3.61	3.73	
G	0.190	0.210	4.83	5.33	
Η	0.110	0.130	2.79	3.30	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.14	1.39	
Т	0.235	0.255	5.97	6.48	
U	0.000	0.050	0.000	1.27	

PACKAGE DIMENSIONS

TO-220 FULLPACK CASE 221D-03 ISSUE G



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M. 1982.

2. CONTROLLING DIMENSION: INCH 3. 221D-01 THRU 221D-02 OBSOLETE, NEW

STANDARD 221D-03.

	INCHES		INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX		
Α	0.625	0.635	15.88	16.12		
В	0.408	0.418	10.37	10.63		
С	0.180	0.190	4.57	4.83		
D	0.026	0.031	0.65	0.78		
F	0.116	0.119	2.95	3.02		
G	0.100 BSC		2.54 BSC			
н	0.125	0.135	3.18	3.43		
J	0.018	0.025	0.45	0.63		
K	0.530	0.540	13.47	13.73		
L	0.048	0.053	1.23	1.36		
Ν	0.200 BSC		5.08 BSC			
Q	0.124	0.128	3.15	3.25		
R	0.099	0.103	2.51	2.62		
S	0.101	0.113	2.57	2.87		
U	0.238	0.258	6.06	6.56		

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